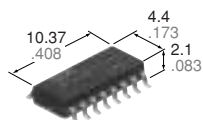


NAIS

DAA (Data Access Arrangement) circuit package. SOP 16-pin type.

GU PhotoMOS (AQS210PS)



mm inch

- (1) PhotoMOS Relay (for hookswitch, dial pulse)
- (2) Optocoupler (for ring detection)
- (3) Darlington for transistor (for electronic inductance)
- (4) Diode bridge (for polarity protection)

2. Ultra-small package size

2. SO package 16-Pin type in super miniature design

The device comes in a super-miniature SO package 16-Pin type measuring (W)4.4 × (L)10.37 × (H) 2.1mm (W).173 × (L).408 × (H).083inch

3. Ideal for PC card and Fax/Modem applications

The small size provides additional space for increased functionality. The new device has been specifically designed for the PCMCIA embedded and handheld device markets.

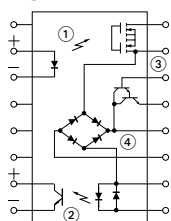
4. Tape and reel

The device comes standard in tape and reel (1,000 pcs./reel) for use with automatic insertion machines.

5. Internal zener diode type also available

FEATURES

1. DAA (Data Access Arrangement) circuit package



TYPICAL APPLICATIONS

- PCMCIA Modem card (Data/fax modem)
- Laptop and notebook computers
- PDA's
- Mobile computing equipment
- Medical equipment
- Security systems
- Meters (Water, Gas, Vending machine)

TYPES

Type	Relay portion Output rating*		Part No.		Packing quantity in tape and reel
	Load voltage	Load current	Picked from the 1/2/3/4/5/6/7/8-pin side	Picked from the 9/10/11/12/13/14/15/16-pin side	
AC/DC type	350V	120mA	AQS210PSX	AQS210PSZ	1,000 pcs.

* Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suffix "X" or "Z" is not needed when ordering; Tube: 50 pcs.; Case: 1,000 pcs.)

(2) For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

1) Relay portion (2, 3, 15, 16 pins)

Item		Symbol	AQS210PS	Remarks
Input	LED forward current	I_F	50mA	
	LED reverse voltage	V_R	5V	
	Peak forward current	I_{FP}	1A	f=100 Hz, Duty factor=0.1%
	Power dissipation	P_{in}	75mW	
Output	Load voltage (peak AC)	V_L	350V	
	Continuous load current	I_L	0.12A	Peak AC,DC
	Peak load current	I_{peak}	0.36A	100 ms (1 shot), V_L = DC
	Power dissipation	P_{out}	400mW	

2) Detector portion (7, 8, 9, 10 pins)

Item		Symbol	AQS210PS	Remarks
Input	LED forward current	I_F	50mA	
	Peak forward current	I_{FP}	1A	f = 100 Hz, Duty factor=0.1%
	Power dissipation	P_{in}	75mW	
Output	Voltage between collector and emitter	BV_{CEO}	30V	
	Power dissipation	P_{out}	150mW	

3) Bridge rectifier portion (10, 11, 12, 15 pins)

Item		Symbol	AQS210PS	Remarks
Forward current		I_F	140mA	
Peak forward current		I_{FP}	500mA	t=10ms
Reverse voltage		V_R	100V	

GU PhotoMOS (AQS210PS)

4) Darlington portion (12, 13, 14 pins)

Item	Symbol	AQS210PS	Remarks
Output voltage	BV_{CEC}	40V	
Collector current	I_c	120mA	$V_{CE}=3.5V$
Power dissipation	P_{out}	500mW	

5) Others

Item	Symbol	AQS210PS	Remarks	
Total power dissipation	P_T	650mW		
I/O isolation voltage	V_{iso}	1500V AC		
Temperature limits	Operating	T_{opr}	$-40^{\circ}C$ to $+85^{\circ}C$ $-40^{\circ}F$ to $+185^{\circ}F$	Non-condensing at low temperatures
	Storage	T_{stg}	$-40^{\circ}C$ to $+100^{\circ}C$ $-40^{\circ}F$ to $+212^{\circ}F$	

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

1) Relay portion (2, 3, 15, 16 pins)

Item		Symbol	AQS210PS	Condition
Input	LED operate current	Typical	0.9mA	$I_L=Max.$
		Maximum	3mA	
	LED turn off current	Minimum	0.4mA	$I_L=Max.$
		Typical	0.8mA	
LED dropout voltage	Typical	1.25 (1.14 V at $I_F=5mA$)	$I_F=50mA$	
	Maximum	1.5V		
Output	On resistance	Typical	18Ω	$I_F=5mA$ $I_L=Max.$ Within 1 s on time
		Maximum	25Ω	
	Off state leakage current	Maximum	I_{Leak}	
Transfer characteristics	Turn on time*	Typical	0.23ms	$I_F=5mA$ $I_L=Max.$
		Maximum	2.0ms	
	Turn off time*	Typical	0.04ms	$I_F=5mA$ $I_L=Max.$
		Maximum	1.0ms	

Note: Recommendable LED forward current $I_F=5mA$.

2) Detector portion (7, 8, 9, 10 pins)

Item		Symbol	AQS210PS	Condition
Input	LED operate current	Typical	2mA	$I_c=2mA$ $V_{CE}=0.5V$
		Maximum	6mA	
	LED turn off current	Minimum	5μA	$I_c=1μA$ $V_{CE}=5V$
		Typical	35μA	
LED dropout voltage	Typical	1.14 (1.25 V at $I_F=50mA$)	$I_F=5mA$	
	Maximum	1.5V		
Output	Saturation voltage	Typical	0.08V	$I_F=15mA$ $I_c=2mA$
		Maximum	0.5V	
	Off state leakage current	Typical	0.01nA	$I_F=0$ $V_{CE}=5V$
		Maximum	500nA	
Current transfer ratio	Minimum	33%	$I_F=5mA$ $V_{CE}=0.5V$	
	Typical	100%		
Transfer characteristics	Turn on time*	Typical	0.01ms	$I_F=5mA$ $V_{CE}=5V$ $I_c=2mA$
	Turn off time*	Typical	0.03ms	$I_F=5mA$ $V_{CE}=5V$ $I_c=2mA$

3) Diode Bridge portion (10, 11, 12, 15 pins)

Item	Symbol	AQS210PS	Condition
Forward dropout voltage	Typical	0.9V	$I_F=120mA$
	Maximum	1.2V	
Reverse leakage current	Maximum	I_R	$V_R=100V$

GU PhotoMOS (AQS210PS)

4) Darlington transistor portion (12, 13, 14 pins)

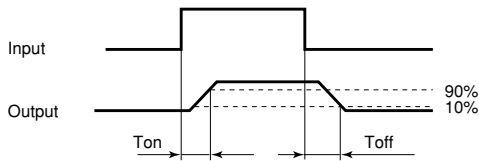
Item		Symbol	AQS210PS	Condition
Saturation voltage	Typical	$V_{CE(SAT)}$	0.73V	$I_C=120mA$
	Maximum		1.5V	
Collector leakage current	Maximum	I_{CEX}	1 μ A	$V_{CE}=10V, I_B=0mA$
DC current gain	Minimum	h_{FE}	10,000	$I_C=120mA$ $V_{CE}=10V$
	Typical		30,000	
Total harmonic distortion	Maximum	—	-80dB	$I_C=40mA, f_o=300Hz$ @-10dBm

5) Others

Item		Symbol	AQS210PS	Condition
Transfer characteristics	I/O capacitance	Typical	C_{iso}	—
		Maximum		
	Initial I/O isolation resistance	Minimum	R_{iso}	1,000M Ω

*Turn on/Turn off time

For type of connection



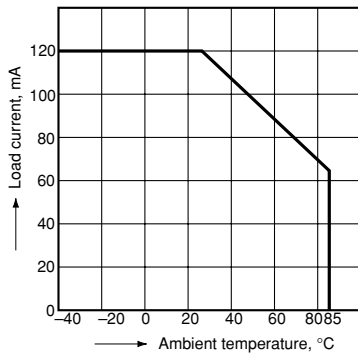
- For Dimensions
- For Schematic and Wiring Diagrams
- For Cautions for Use

REFERENCE DATA

[1] Relay portion (2, 3, 15, 16 pins) [AQS210PS]

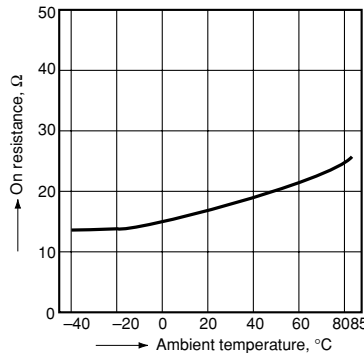
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



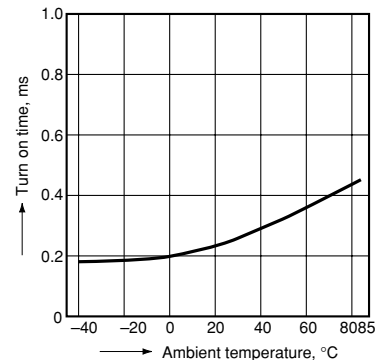
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 15 and 16
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



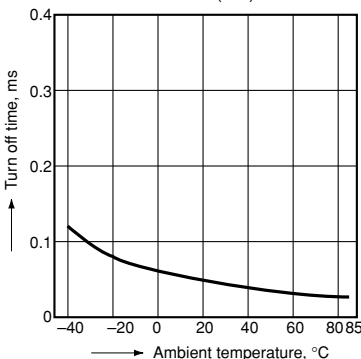
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



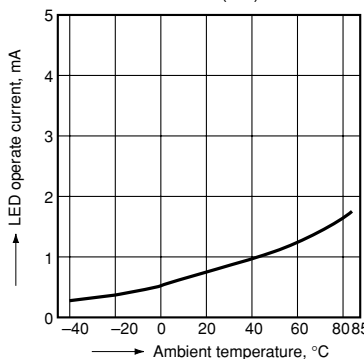
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



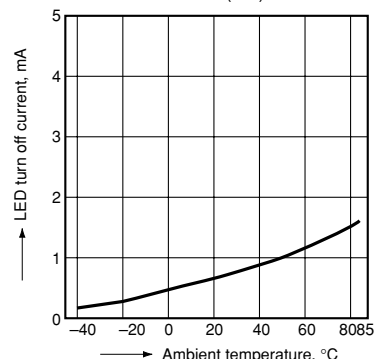
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



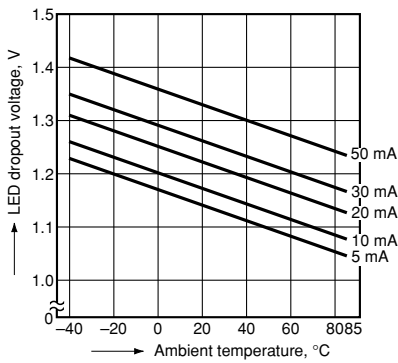
6. LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)

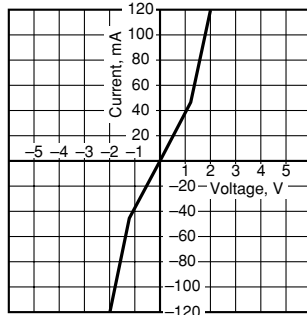


GU PhotoMOS (AQS210PS)

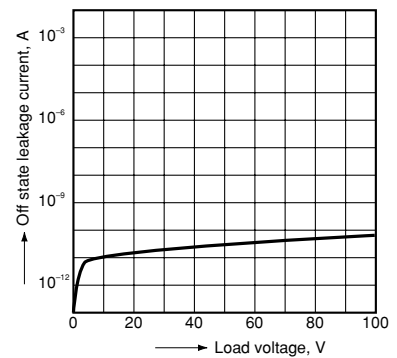
7. LED dropout voltage vs. ambient temperature characteristics
LED current: 5 to 50 mA



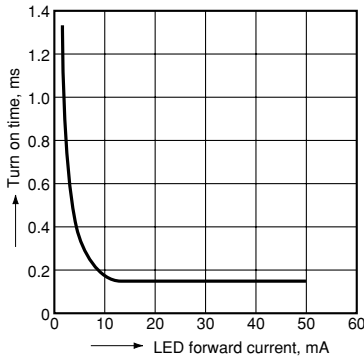
8. Voltage vs. current characteristics of output at MOS portion
Measured portion: between terminals 15 and 16
Ambient temperature: 25°C 77°F



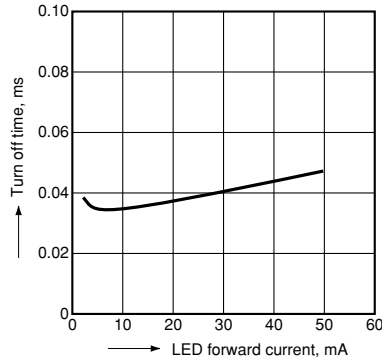
9. Off state leakage current
Measured portion: between terminals 15 and 16
Ambient temperature: 25°C 77°F



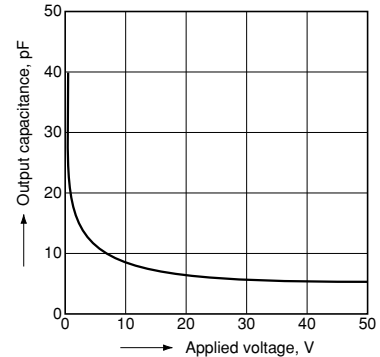
10. LED forward current vs. turn on time characteristics
Measured portion: between terminals 15 and 16
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. LED forward current vs. turn off time characteristics
Measured portion: between terminals 15 and 16
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F

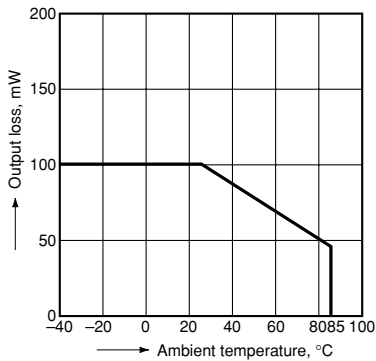


12. Applied voltage vs. output capacitance characteristics
Measured portion: between terminals 15 and 16
Frequency: 1 MHz; Ambient temperature: 25°C 77°F

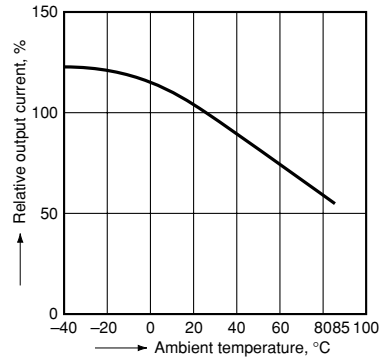


[2] Detector portion (7, 8, 9, 10 pins)

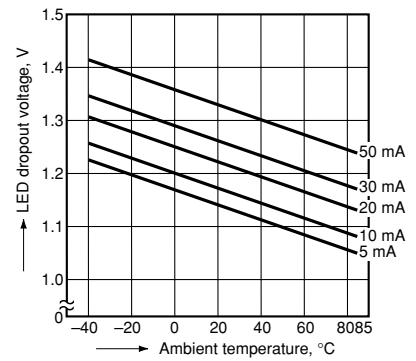
1. Output loss vs. ambient temperature characteristics
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



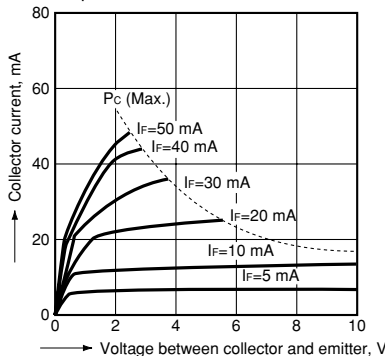
2. Relative output current vs. ambient temperature characteristics
Measured portion: between terminals 7 and 8
I_F = 5 mA, V_{CE} = 0.5 V DC



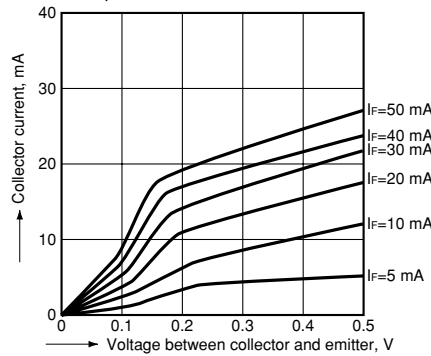
3. LED dropout voltage vs. ambient temperature characteristics
LED current: 5 to 50 mA



4-1. Collector current vs. voltage between collector and emitter characteristics (I_C-V_{CE})
Measured portion: between terminals 7 and 8
Ambient temperature: 25°C 77°F



4-2. Collector current vs. voltage between collector and emitter characteristics (I_C-V_{CE})
Measured portion: between terminals 7 and 8
Ambient temperature: 25°C 77°F



5. Off state leakage current
Measured portion: between terminals 7 and 8
I_F = 0 mA
T_a = 25°C 77°F

